Bolom etric technique for high-resolution broadband m icrow ave spectroscopy of ultra-low -loss sam ples

P.J.Tumer, D.M.Broun, Saeid Kamal, M.E.Hayden, J.S.Bobowski,

Department of Physics and Astronomy, University of British Columbia, Vancouver, B.C., Canada V6T 121

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A novel low tem perature bolom etric m ethod has been devised and in plan ented for high-precision m easurem ents of the m icrow ave surface resistance of sm all single-crystal platelet sam ples having very low absorption, as a continuous function of frequency. The key to the success of this non-resonant m ethod is the in-situ use of a norm all metal reference sample that calibrates the absolute rf eld strength. The sample tem perature can be controlled independently of the 1.2 K liquid helium bath, allowing for m easurem ents of the tem perature evolution of the absorption. However, the instrum ent's sensitivity decreases at higher tem peratures, placing a lim it on the useful tem perature range. U sing this method, the minim um detectable power at 1.3 K is 1.5 pW, corresponding to a surface resistance sensitivity of 1 for a typical 1 mm 1 mm platelet sample.

I. IN TRODUCTION

In this article we describe an apparatus designed for the continuous-frequency measurement of low temperature electrom agnetic absorption spectra in the m icrow ave range. The motivation to develop this instrum ent com es from a desire to resolve, in great detail, the m icrow ave conductivity of high-quality single crystals of high-T $_{\rm c}$ cuprate superconductors. However, the technique we describe should nd a wealth of applications to other condensed matter systems, providing a means to explore the dynamics of novel electronic states with unprecedented resolution. The possibilities include: the physics of the m etal { insulator transition, where charge localization should lead to frequency scaling of the conductivity; electron spin resonance spectroscopy of crystal eld excitations; ferrom agnetic resonance in novelm agnetic structures; and cyclotron resonance studies of Ferm i surface topology. In addition to the cuprate superconductors, other natural possibilities in the area of superconductivity include heavy ferm ion and ruthenate m aterials, as well as high resolution spectroscopy of low -frequency collective excitations such as Josephson plasm ons and orderparam eter collective m odes.

Early m icrow ave m easurem ents on high quality single showed that cooling through crystals of YB a_2 C u_3 O $_7$ 90 K decreased the surface resistance very rapidly, Т_с by four orders of m agnitude at 2.95 GHz, reaching a low tem perature value of several .¹ Resolving this low absorption in the microwave region has provided a technical challenge that has been successfully m et overm ost of the tem perature range below T_c by the use of high precision cavity-perturbation techniques.^{2,3} In these experim ents, the sam ple under test is brought into the m icrow ave elds of a high quality-factor resonant structure made from superconducting cavities or low -loss dielectric pucks. A lim itation of such techniques is that the resonator is generally restricted to operation at a single xed frequency, therefore requiring the use of m any separate experim ents in order to reveal a spectrum . Furtherm ore, a very gen-

eral lim itation of the cavity perturbation m ethod is that the dissipation of the unknown sample must exceed the dissipation of the cavity itself in order to be measured with high precision | a very strong dem and for a high quality superconductor in the T ! 0 lim it. The measurement of the residual absorption in superconductors is challenging at any frequency: in the case of infra-red spectroscopy the problem becom es that of measuring values of relectance that are very close to unity. The challenge lies in the calibration of the measurement, and in both m icrow ave and infra-red work, one relies on having a reference sample of known absorption to calibrate the loss in the walls of the microwave resonator or the infrared re ectance. Despite these limitations, resonant microw ave techniques are the only methods with su cient sensitivity to m easure the evolution of the m icrow ave absorption over a wide tem perature range. In a recent e ort by our group, ve superconducting resonators were used to map a coarse conductivity spectrum from 1 GHz to 75 G H z in exceptionally clean samples of Y B a₂C u₃O 6.99 from 4 K to 100 K.⁴ This work revealed low tem perature quasiparticle dynam ics inconsistent with simple models ofd-wave superconductivity, whose key signatures appear in the frequency dependence of the conductivity.^{5,6,7} The failure of simple theories to give a complete description of the tem perature evolution and shape of the conductivity spectra in the best quality samples has driven us to develop the technique described here, with the result that we can now resolve low -tem perature m icrow ave conductivity spectra in unprecedented detail.

B olom etric detection is a natural method for measuring the surface resistance spectrum over a continuous frequency range. For any conductor, the power absorption in a microwave magnetic eld is directly proportional to the surface resistance R_s :

$$P_{abs} = R_{s} H_{rf}^{2} dS; \qquad (1)$$

where H_{rf} is the rm s.m agnitude of the tangentialm agnetic eld at the surface S.As a result, a measurement of

R. Harris, D. C. Morgan, J. S. Preston, D. A. Bonn, and W. N. Hardy

the tem perature rise experienced by a weakly-therm allyanchored sample exposed to a known microwave magnetic eld H_{rf} directly gives R_s . To enhance rejection of spurious tem perature variations, the rf power should be am plitude modulated at low frequency and the resulting tem perature oscillations of the sample detected synchronously.

W e note that as part of a pioneering study of superconducting A L a sim ilar bolom etric m icrow ave technique was used by Biondi and Garfunkel to exam ine the detailed tem perature dependence of the superconducting gap frequency.⁸ This earlier experiment had the simplifying advantage of m easuring the absorption by a large waveguide made entirely from single crystalline Al. Unfortunately, in more complicated materials such as the multi-elem ental cuprate superconductors, the best quality samples can only be produced as small single crystals. M ore recently, frequency-scanned bolom etric m easurem ents have proven useful in probing collective excitations in sm all sam ples of high-T c cuprates at frequencies above 20 GHz where the absorption is larger and much easier to m easure.9 These techniques, how ever, have not focussed on the challenge of resolving the low temperature absorption of high-quality single crystals across a broad frequency range.

A characteristic feature of many electronic materials of current interest is reduced dim ensionality, which gives rise to highly anisotropic transport coe cients. W hen making microwave measurements, a well-de ned geom etry must be chosen in order to separate the individual components of the conductivity tensor, and also to ensure that dem agnetization e ects do not obscure the m easurem ent. One particularly clean approach that has been widely used places the sample to be characterized near a position of high symmetry in a microwave enclosure, in the quasi-hom ogeneous microw ave magnetic eld near an electric node. O ften, single crystal sam ples grow naturally as platelets having a broad \hat{a} b plane crystal face and thin C-axis dimension, and demagnetization effects are minimized if the broad face of the sample is aligned parallel to the eld. In response to the applied rf magnetic eld, screening currents ow near the surface of the sample along the broad â or b face and must necessarily ow along the ĉ direction to com plete a closed path. In some cases, it is desirable to work with samples that are very thin, rendering the c-axis contribution negligible. A lternatively, by varying the aspect ratio of the sam ple by either cleaving or polishing, one can m ake a series of measurem ents to disentangle the di erent crystallographic contributions, without having to change sam ples. For example, in the cuprate superconductors, the conductivity parallel to the two dimensional CuO₂ plane layers can be several orders of m agnitude larger than that perpendicular to the weakly-coupled planes. Typical asgrown crystaldim ensions are 1:0 1:0 :01 mm³. For this aspect ratio, experiments where a sample was cleaved into many pieces showed that the c-axis contribution is unimportant.¹⁰ W e note here that all measurements presented in this article employ the low-dem agnetization sample orientation discussed above.

The broadband surface-resistance measurement technique we describe in the following sections provides three distinct technical advances over previous bolom etric approaches: a uniform microwave eld con guration in the sample region that permits the separation of an isotropic conductivity components; the use of an in-situ reference sample that calibrates the microwave eld strength at the sample absolutely; and very high sensitivity a orded by the choice of a resistive bolom eter optim ized for the low-tem perature range and mounted on a miniaturized them al stage. These features of our apparatus perm it precision m easurem ents of the absolute value of R_s (!; T) in very-low-loss samples down to 12 K and over the frequency range 0.1-21 GHz. W e will brie y dem onstrate that this range captures the key frequency window for long-lived nodal quasiparticles in extremely clean sam ples of $Y B a_2 C u_3 O_7$, and to further demonstrate the perform ance and versatility of the apparatus, we also show an example of zero-eld electron-spin-resonance spectroscopy.

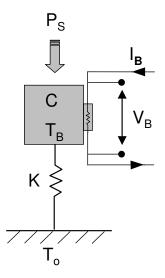


FIG.1: A simple them alm odel consisting of a heat capacity C them ally isolated from base temperature T_0 by a weak them all link of conductance K. The resistive bolom eter is them ally anchored to C and monitors its temperature, $T_{\rm B}$, which is elevated above T_0 by a constant current bias $I_{\rm B}$ passing through the bolom eter. The absorption of incident signal power $P_{\rm s}$ causes heating in C, detectable as a temperature rise through a change in the voltage $V_{\rm B}$.

II. BOLOMETRIC DETECTION

It is instructive to calculate the minimum power detectable by a simple thermal stage, the temperature of which is monitored by a resistive bolom eter, as depicted in Fig. 1.¹¹ The bolom eter has a resistance R_B and is in thermal equilibrium with a larger heat capac-

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ity C representing contributions from the sample, its holder, and the weak therm al link. This combination is weakly connected, via a therm al conductance K, to a heat sink maintained at base temperature T_0 . The bolom eter is heated to its operating temperature T_B by a bias power P_B = $I_B^2\,R_B$, where I_B is the xed bolom eter bias current. For this analysis we do not consider feedback e ects, although they are very important in the special case of transition edge bolom eters. 12 As a result, we consider a con guration where I_B provides only modest self-heating of the bolom eter, such that $(T_B \quad T_0)=T_0$. 1. An incident signal power P_S raises the temperature by an amount $T_B = P_S = K$, caus-

ing a change in the readout voltage across the bolom eter $V_B = I_B (dR_B = dT) T_B = I_B (dR_B = dT)P_S = K . We then de ne a threshold detectable signal level that is equal to the therm al noise n generated in a bandwidth$

in the bolom eter, $\frac{2}{n} = 4k_B T_B R_B$. It is then possible to write an expression for the minimum detectable power $P_S^{m \ in}$ in terms of the dimensionless sensitivity of the bolom eter $S_d = T=R \ jdR=dT \ j$ typically of the order of unity, the noise power $P_n = k_B T_B$, and the bolom eter bias power P_B :

$$P_{\rm S}^{\rm m in} = \frac{2}{S_{\rm d}} p_{\rm n} P_{\rm B} ; \qquad (2)$$

From this expression one im m ediately sees that it is desirable to m inim ize both the bias and noise powers, within the combined constraints of maintaining the bolom eter tem perature at T_B and keeping the therm al response time xed at a suitably short value. By m iniaturization of the sample holder, the bias power required to reach a given tem perature can be considerably reduced, while at the same time maintaining a practical therm altime constant. The noise power is limited intrinsically by the therm al (Johnson) noise from the bolom eter resistance at tem perature T_B . However, most real sensors show substantial excess noise, and the Cernox 1050 sensor¹⁴ used in the present in plem entation of our experiment is no exception, showing approximately 40 dB of excess noise in the presence of a 1.3 A bias current. This com pletely accounts for the discrepancy between the minimum detectable power at 1.3 K of 17 fW calculated using Eq.2 assuming only Johnson noise, and the experimentally determ ined value of 1.5 pW .

III. BROADBAND ABSORPTION MEASUREMENT APPARATUS

For our method of bolom etric detection to be most useful, it is necessary to deliver microwaves to the sam – ple across a broad range of frequency and, at the sam e time, not only accurately control the polarization of the microwave eld at the sam ple, but also maintain a xed relationship between the eld intensity at the sam ple under test and the eld intensity at the reference sam ple. E ssential to this is the design of the microwave waveg-

uide. We use a custom -m ade transm ission line, shown in cross-section in Fig. 2, that consists of a rectangular outer conductor that m easures 8.90 mm 4.06 m m in cross-section and a broad, at centre conductor, or septum, that measures 4.95 mm 0.91 mm. This supports a TEM mode in which the magnetic elds lie in the transverse plane and form closed loops around the centre conductor, setting a xed relationship between the microw ave eld strengths on either side of the septum. The line is term inated by shorting the centre conductor and outer conductor with a at, m etallic endwall. This enforces an electric eld node at the end of the waveguide, ad jacent to which we locate the sm all platelet sam ple and reference, with their at faces parallel and very close to the endwall. The broad centre conductor ensures spatially uniform elds over the dimensions of the sample, making it possible to drive screening currents selectively along a chosen crystallographic direction. The electrodynam ics of the rectangular waveguide are discussed in more detail in Appendix B. A strong variation in the power delivered to the sample as a function of frequency arises due to standing waves in the microwave circuit. In order to properly account for this, we have incorporated an in-situ norm al-m etal reference sam ple of know n surface resistance that acts as an absolute powerm eter. This second sample is held in a position that is electrom agnetically equivalent to the that of the test sample, on a separate therm al stage.

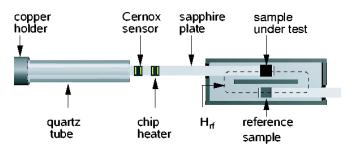


FIG.2: Schem atic cross-section of the term inated coaxial line region showing the sample and reference materials suspended on sapphire plates in symmetric locations in the rf magnetic eld. The sapphire plate is epoxied into the bore of a quartz tube which therm ally isolates it from the copper holder, xed at the temperature of the 12 K helium bath.

O ne of the challenges of cryogenic m icrow ave absorption m easurem ents on sm all, low -loss sam ples is the design of the sam ple holder, which m ust m easure and regulate the sam ple tem perature, and yet contribute negligible dissipation compared to the sam ple. A widely used technique that satis es these requirem ents is that of a sapphire hot- nger in vacuum,¹³ allow ing the therm om etry to be electrom agnetically shielded from the m icrow ave elds. In our apparatus, the sam ple holder is inserted through a hole that is beyond cut o for all operating frequencies. For ac calorim etric m easurem ents, the design of the therm al stage is critical in setting the sensitivity of the system. The experim ental arrangem ent

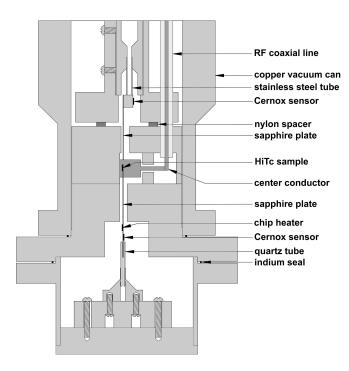


FIG.3: Scale drawing of the assembled apparatus indicating the details of the vacuum can and sample region. The alloy reference sample is not visible in this cut-away view.

is shown schematically in Fig. 2 with the sample under test xed on the end of a 100 m thick sapphire plate using a tiny amount of vacuum grease.¹⁵ The plate extends 17 mm from the sample to where it is epoxied into the bore of a 12 mm diam eter quartz glass tube that acts as a therm alweak-link to the liquid helium bath. A Cernox therm om eter and a 1500 surface-m ount resistor used as a heater¹⁶ are glued directly onto the sapphire plate with a very thin layer of Stycast 1266 epoxy,¹⁷ ensuring intim ate therm alcontact with the sapphire and hence the sam ple. W e use 0.05 m m diam eter N bT i superconducting electrical leads to the therm om eter and heater for their very low therm al conductance, which is in parallel with the quartz weak-link.

The microwave circuit is powered by a Hewlett-Packard 83630A synthesized sweeper (0.01-26.5 GHz) com bined with either an 8347A (0.01-3GHz) or 8349B (2-20 GHz) amplier, generating up to 23 dBm of rfpower across the spectrum . Approximately 2 m of 0.141^q stainless steel coaxial line¹⁸ delivers power from the amplier down the cryostat to the vacuum can where it is soldered into the rectangular line (see Fig. 3). The rm s. microw ave m agnetic eld am plitude at the sam ples is typically 10² 0 ersteds, which generates K modulations in the sam ple-stage tem perature for a typical high quality 1 mm^2 high-T_c sample having a low frequency R_s value of 1

An assembled view of the low temperature apparatus including the m icrow ave transm ission line and the positions of the sam ple and reference holders is provided in

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Fig. 3. The sapphire plates that support both the test sample and reference sample are inserted through 4 mm cut-o holes into the microw ave magnetic eld. The rectangular coaxial line consists of a centre conductor m ade from a 0.91 mm thick copper plate soldered at one end onto the centre conductor of the 0.141^q sem i-rigid coaxial line, and at the other end into the wall of the copper cavity that com prises the outer conductor of the transm ission line. To m in im ize the rf power dissipated in the low tem perature section of transm ission line, the entire surface exposed to m icrow ave radiation, including the nal15 cm of sem i-rigid coaxial line, was coated with PbSn solder, which is superconducting below 7 K.During experiments, the vacuum can is completely immersed in a pum ped liquid helium bath having a base tem perature of 1.2 K.

The selection of a reference material for low-frequency work must be made carefully. Initially, we chose sam ples cut from commercially available stainless-steel shim stock, a common choice in infrared spectroscopy work. Calibration experiments produced erratic results which were eventually traced to the presence of anisotropic residual magnetism in the stainless steel. Subsequently, we produced our own reference material, choosing an AgAu alloy (70:30 at.% made from 99.99% pure starting materials), because it exhibits a very simple phase diagram that guarantees hom ogeneity.¹⁹ By using an alloy, we ensure that the electrodynam ics remain local at microw ave frequencies, avoiding the potential com plications arising from the anom alous skin e ect.²⁰ Our sam ple was cut from a 93 5 m thick foilhaving a measured residual dc resistivity value of = 5.28 0:3 cm, constant below 20 K .

W hile the therm al stage for the reference sample is sim ilar in design to that used for the sample under test, it uses a higher conductance stainless steel therm alw eaklink (in place of the quartz tube), since the dissipation of the norm alm etal calibration sample is orders of m agnitude larger than that of a typical superconducting sam ple. Because the apparatus was in plem ented as a retrot to an existing experim ent, the reference therm al stage had to be mounted directly onto the body of the trans-

m ission line structure. A lthough the cavity walls are superconducting to reduce their absorption, we use a nylon spacer to therm ally isolate the base of the reference from the transm ission line to avoid direct heating. The heatsinking of the reference base to the helium bath is made using a separate copper braid that is not visible in Fig. 3.

A sconsidered previously in our generic analysis, we operate the Cemox bolom eter with a constant dc current bias, typically a few A, provided by the series com bination of an alkaline battery (1.5 V or 9 V) and bias resistor whose value is much larger than that of the Cernox sensor. With the helium bath under temperature regulation, the choice of bias power sets the tem perature of the sample for a given experiment, with no other tem perature control necessary. All electrical leads into the cryostat are shielded twisted pairs of insulated m anganin wire, and true four-point resistance m easurem ents are made on all sensors. The voltage signal appearing on the Cernox therm om eter is am pli ed outside the cryostat by a carefully shielded and battery-powered circuit. W e use a two-stage cascaded am pli er with one A nalog Devices AD 548 operational ampli er per stage, chosen because these are readily available, low-noise ampli ers. The dc level is nulled between stages to prevent saturation, and the total gain is 10^4 . The amplied signal, corresponding to the tem perature m odulation of the sam ple, is then dem odulated with a Stanford Research System s SR 850 digital lock-in ampli er that is phase-locked with the rf-power amplitude modulation. There are two such systems, one for the sample and one for the reference m easurem ents. The entire experim ent is operated under com puter control when collecting data.

IV . $\operatorname{CALIBRAT}$ IO N

Two steps are necessary for an absolute calibration of the surface resistance of an unknown specim en from the measured temperature-rise data. The rst is to calibrate the absolute power sensitivity of the sam ple and reference therm al stages at the actual operating tem perature and modulation frequency. This is achieved using the sm all in-situ heater to drive well-characterized heat pulses that m im ic absorption by the sam ple, while at the same time measuring the corresponding temperature response. The second step requires the calibration of the magnetic eld strength at the sample, at each frequency, using the known absorption of the reference sample. We exploit the fact that the m etallic reference sam ple experiences the same incident microwave eld H_{rf} as the sam ple under test, guaranteed by conservation of magnetic ux. This ensures that taking the ratio of the absorbed power per unit surface area of each sam ple provides the ratio of the surface resistance values:

$$\frac{P_{abs}^{sam}}{P_{abs}^{ref}} = \frac{R_s^{sam} A^{sam}}{R_s^{ref} A^{ref}} :$$
(3)

The surface resistance of the unknown sample R $_{\rm s}^{\rm sam}$ (!) is then trivially found by multiplying the power-absorption ratio, shown in Fig. 4, by R $_{\rm s}$ (!) of the metallic reference sample calculated using the classical skin-e ect form ula R $_{\rm s}$ (!) = 1 $_{\odot}$ =2 where !=2 is the frequency and $_{\odot}$ is the permeability of free space. The raw power-absorption spectra, shown in the rst two panels of Fig. 4, highlight the necessity of the reference sample. The absorption spectra of the samples is completely masked by the large amplitude variations of H $_{\rm rf}$ caused by the standing waves in the microw ave circuit.

A n essential test of the m ethod is to m ake a frequencyscanned m easurem ent w ith identical sam ples m ounted on the sam ple and the reference stages. The result should be a frequency-independent ratio across the spectrum, equal to unity for sam ples with the same surface area. 5

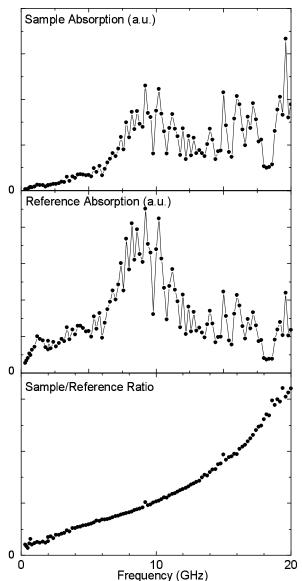


FIG.4: Raw absorption spectra corresponding to the temperature rise of the sample. Taking the ratio of the two signals accounts for the strong frequency dependence of H $_{\rm rf}$ introduced by standing waves in the transmission line. The remaining frequency dependence of the ratio is due to the di erent R $_{\rm s}$ (!) spectra of the two sam ples.

In Fig. 5 we show such a measurement using two thinplatelet samples of our AgAu reference alloy, both at the base temperature of 1.2 K. The data reveals ratio of 0.82 in the cryogenic apparatus, due to the fact that the centre conductor is o set from centre by 0.1 mm in the term ination region, intensifying the elds on one side relative to the other. This scale factor must be included in the calibration of all experimental data. The sharp resonance seen in the ratio at 22.5 G H z indicates the presence of a non-TEM electrom agnetic mode in the sample cavity that breaks the symmetry in eld strength between sample and reference positions. For our present design,

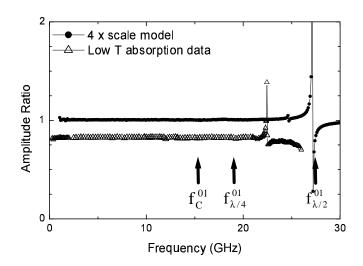


FIG.5: Ratio of the sample absorption to reference absorption for identical sam ples, com pared to m easurem ents of the eld am plitude at equivalent positions in a 4 scale model. (Frequencies for the scale model have been scaled by a factor of 4 for the com parison.) The ratio technique is seen to break down with a sharp resonance in both cases. The origin of these resonances, which lim it the useful frequency range of the apparatus, is discussed in detail in Appendix B and show n to be due to the presence of standing waves of the T E $_{01}$ waveguide mode. For this mode, the three arrows indicate: the cut-o frequency $f_{C}^{01} = 15:38 \text{ GHz}$ at which the mode is rst free to propagate; its quarter-wave resonance frequency $f_{=4}^{01} = 19:11 \text{ GHz}$, for open-circuit term ination conditions; and the half-wave resonance frequency $f_{=2}^{01} = 27.4 \text{ GHz}$, for short-circuit term ination conditions. The =4 and =2 resonance frequencies bracket the observed resonances. The scale model, which has a large transition capacitance between circular and rectangular coax sections, is seen to fall at the high end of the range.

this sets the upper frequency lim it of operation.

In an attempt to gain further insight into the eld congurations in the transmission line, and to understand how the higher order waveguide modes lim it the upper frequency range, we built a scale m odel of the setup having all dimensions larger than those of the cryogenic apparatus by a factor of four. For com parison, a frequency scan of the model structure is included in Fig. 5, using loop-probes in the positions of the samples. The data show that the non-TEM -m ode resonance occurs at 27 GHz, considerably higher than in the low temperature experiment. It turns out that the breakdown of the sam ple-reference symmetry occurs not at the frequency at which higher order waveguide modes rst propagate in our structure, but at the frequency at which they form a resonant standing wave. A full discussion of this is given in Appendix B.

A number of other experimental tests were important to verify the proper operation of the system. Frequency scans without samples mounted on the sapphire stages con med that background absorption due to the sapphire and tiny amount of vacuum grease used to a x

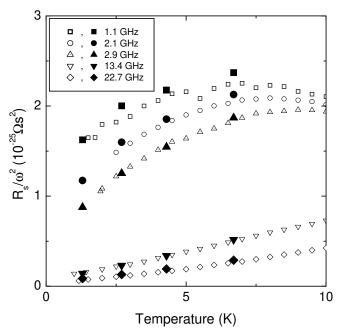


FIG. 6: Comparison of measurements made on the same sample of Y B a_2 C u_3 O $_{6:50}$ using the broadband bolometric experiment (solid symbols) with those from vemicrowave resonators (open symbols). The agreement between methods is excellent. The data is plotted as R $_{\rm s}$ (!)=!² to remove the frequency dependence associated with super uid screening.

the samples is negligible it is unmeasurable at low frequency, and contributes no m ore than 2 to an R $_{\circ}$ m easurement at 21 GHz. Scans without a sample also con med that no signi cant leakage heat current propagates to the therm om eters directly from the m icrow ave waveguide. The high therm al stability of the cryostat system is due in part to the very large e ective heat capacity of the pum ped 4 litre liquid-helium bath at 1.2 K. In addition, it is always in portant to make certain the tem perature modulations of the samples are su ciently sm all that the response of the therm al stages rem ains in the linear regime. Furtherm ore, measurements with the same sample located in di erent positions along the sapphire plate, with up to 0.5 mm displacement from the central location in the waveguide, con med that there is enough eld hom ogeneity that our sample alignment procedure using an optical microscope is su cient, and that sam ples of di erent sizes experience the sam e elds.

A very convincing veri cation of the technique is provided by the ability to com pare broadband R_s (!; T) data with m easurements of the same sample in ve dierent high-Q microwave resonators. These experiments probe the tem perature dependence of the absorption to high precision at a xed microwave frequency: however, the determination of the absolute value of R_s is limited to about 10% as discussed previously. The bolom etric method has the advantage of being able to measure a true spectrum because the dominant uncertainty, the absolute surface resistance of the reference sample, enters

as a scale factor that applies across the entire frequency and tem perature range. A detailed discussion of the uncertainties in the bolom etry data will be presented in the subsequent section. Figure 6 shows that there is very good agreem ent of both the tem perature and frequency dependence of the surface resistance as m easured independently by the xed-frequency and broadband experim ents.

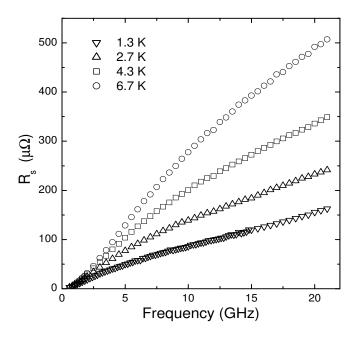


FIG. 7: B roadband m easurements of the m icrowave surface resistance spectrum of Y B a_2 C u_3 O $_{6:50}$ obtained with the bolom etric apparatus below 10 K. The low frequency absorption approaches the resolution limit of the apparatus, while the upper frequency limit is imposed by the resonance in the m icrowave structure.

V. PERFORMANCE

Figure 7 presents an example of high resolution broadband measurements of the frequency-dependent and tem perature-dependent surface resistance of a superconducting sample.²¹ This particular data set is for â-axis currents in a YBa₂Cu₃O_{6:50} single crystal ($T_c = 56$ K) having dimensions 1.25 0.96 0.010 mm³. The data span the range 0.6-21 GHz, limited at high frequency by the resonance in the system , and at low frequency by the sm all dissipation of the sam ple, which approaches the resolution lim it of the experim ent. At 1 G H z, the values for the statistical rm .s. uncertainty in surface resistance, R_s , are about 0.2, 0.4, 0.6, and 1.3 for T = 1.3, 2.7, 4.3, and 6.7 K respectively. Error bars have been om itted from the gure for clarity. System atic contributions to the uncertainty enter as overall scale factors in the R_s data and are attributed to an uncertainty in the DC resistivity of the thin AgAu alloy foil used as a reference

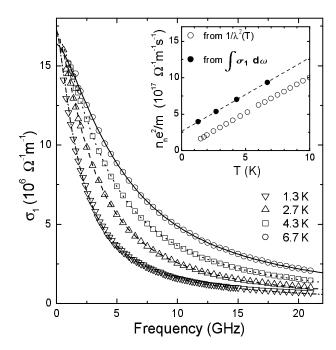


FIG. 8: The real part of the microwave conductivity $_1(!;T)$ extracted from the broadband $R_s(!;T)$ measurements. We use the self-consistent thing procedure described in Appendix C to properly account for contributions to eld-screening by the quasiparticles.

sample (5%), the surface area of the samples (1%), and the absolute power sensitivity of the therm all stage (1%).

The frequency dependence observed in $R_s(!)$ is due to absorption by quasiparticles therm ally excited from the super uid condensate. The quantity of fundam ental theoretical interest is the real part of the conductivity spectrum $_1(!)$, which must be extracted from the experin entally measured R $_{\rm s}$ (!) data. A thorough discussion of the method we use to do this is given in Appendix C but, to rst approximation, the shape of the conductivity spectrum can be found by dividing R_s (!) by a factor of $!^2$ to account for the screening of the applied eld by the super uid. Figure 8 shows the conductivity spectra extracted from the R_s (!) data using the complete analysis. It is im m ediately apparent why im proving the sensitivity of the experiment is of the utmost importance. The low frequency region, where the power absorption becom es very sm all, is where the conductivity exhibits the strongest frequency dependence and is most im portant to measure accurately. The spectrum at 1.3 K has a width of the order of 5 GHz, signifying very long quasiparticle scattering times, indicative of the high quality of our YBa₂Cu₃O_{6:50} crystal. For this very clean sam ple, most of the spectral weight resides below the experim ental frequency lim it of 21 GHz at 1.3 K, but the increase in scattering with increasing tem perature quickly broadens the spectra thus motivating future designs capable of probing a broader frequency range. M any cuprate m a-

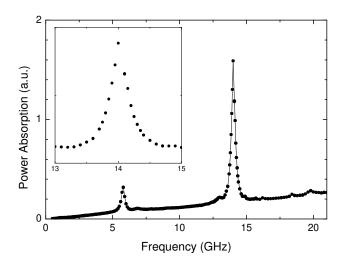


FIG. 9: The electrom agnetic absorption spectrum of a Y $_{0:99}$ G d $_{0:01}$ B a₂C u₃O $_{6:99}$ single crystal at 1.3 K. The spectrum consists of a broad background due to the quasiparticle absorption in the superconductor in addition to the zero eld ESR lines generated by the low concentration of m agnetic G d³⁺ impurities. Only ions residing within a distance of the crystal surface contribute to the signal as the applied rf eld is strongly screened by the superconductor.

terials, such as $B_{12}\,Sr_2C\,aC\,u_2O_{8+}\,$, have scattering rates that are orders ofm agnitude higher and require T H z frequency techniques to probe their dynam ics.^{22}

As a naldem onstration of the sensitivity of the broadband instrument we have described, we include a frequency scan of a superconducting sample that exhibits clearly discemable absorption lines due to zero eld electron spin resonance (ESR) of a low density of magnetic impurities. Gadolinium ions (electron spin S = 7=2) substitute for yttrium, sandwiched between the two CuO planes in the YBaCuO unit cell, and the splitting of the degenerate G d³⁺ hyper ne levels by the crystalline eld provides a very sensitive probe of the local microscopic structure.²³ T hese m easurem ents are typically perform ed in a high eld spectrom eter, but the bolom etric system provides a means of performing zero-eld measurements. Figure 9 shows the 1.3 K absorption spectrum of a 1 mm² Y_{0:99}Gd_{0:01}Ba₂Cu₃O_{6:99} single crystal consisting of a broad background due to the quasiparticle conductivity, essentially unaltered by the presence of the Gd ions, with the ESR absorption peaks superposed. The high signal-to-noise ratio achieved with the experiment allows one to resolve the spectrum in great detail.

The apparatus described here has su cient sensitivity and frequency range for it to be immediately applicable to many other interesting problems in condensed matter physics. These m ight include: the study of low-lying collective modes in metals and superconductors; zero-eld electron spin resonance in correlated insulators; and the study of critical phenomena at the metal (insulator transition and near the zero-temperature magnetic critical points that occur in certain d- and f-electron metals. W ith a little attention to therm aldesign, speci cally the therm al separation of sample stages from the microwave waveguide, the superconducting coatings on the waveguide could be removed and the system used in high magnetic elds. This would open interesting possibilities in the area of metals physics, such as high-resolution cyclotron and periodic-orbit resonance, as well as the study of vortex dynamics and vortex-core spectroscopy in superconductors. Finally, further miniaturization of the experiment should also be possible: the ultimate goal would be to extend the frequency range of this type of spectroscopy so that is joins seam lessly on to the TH z range now accessible using pulsed-laser techniques.

A cknow ledgm ents

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APPENDIX A:FREQUENCY RESPONSE OF DISTRIBUTED THERMAL STAGE

We wish to calculate the temperature response of a simple thermal stage to a sinusoidal heat ux P_{in} = Re $P_0 e^{it}$ superimposed on a static temperature gradient. We consider an arrangement where the isotherm al sam ple stage has neglible therm alm ass and is connected to base temperature by a weak thermal link with distributed heat capacity c_V per unit volume. It is a straightforward extension to include an additional lum ped heat capacity for the isotherm al stage; once the lum ped heat capacity dom inates, the frequency response simplies to that of a single-pole low-pass lter. However, in our case this is unnecessary: for electrodynam ic m easurements at low temperatures, the sample holder is required to be both electrically insulating and highly crystalline, and will therefore have very low heat capacżγ.

Here we consider the one-dimensional problem of a thin bar (the quartz tube in our apparatus) of length 'and cross-sectional area A, with one end xed at a base temperature T_0 while the other end is heated by a heat ux due to sample power absorption. The propagation of a heat current J_Q through the bar is constrained by the continuity equation $(d_Q = (d_X + c_V) (d_T = (d_T = (d_X + d_Y)))$. Together, these lead to the one-dimensional heat equation $(d_T = (d_T = (d_Y + d_Y)))$ is the thermal distribution $(d_T = (d_T + d_Y))$. Together, these lead to the one-dimensional heat equation $(d_T = (d_T + d_Y))$ is the thermal distribution. The propagation $(d_T + d_Y)$ is the thermal distribution $(d_T + d_Y)$. Defining a complex thermal different length $c_T = (d_T + d_Y)$ is the time-dependent part of the temperature.

pro le can be written

$$T(x;t) = Re^{n} Te^{it} \sinh(x=^{\circ})$$
 (A1)

where T is xed by the heat-ux boundary condition: $P_{in} = A (@T=@x) j_{k=} \cdot$. This completely determines the frequency-dependent temperature rise of the sample stage:

$$T(';t) = Re \frac{P_0}{A} e^{jt} \tanh('=)$$
 (A2)

In the low frequency limit, the temperature rise reverts to the usual result:

$$T(';t) = \frac{P_0'}{A}\cos(!t);$$
 (A3)

where, without loss of generality, we have set the phase of the input heat ux to zero. In the high frequency lim it, the therm ald i usion length becomes shorter than the weak link and the temperature rise is reduced, being given by:

T (';t) =
$$\frac{P_0 j j}{A} \cos(!t) = 4$$
 (A 4)

where $j j = p_{-}$. At nite frequencies, part of the heat ux is diverted into the distributed heat capacity of the therm al link. For a xed input power (and hence xed tem perature gradient at the end of the therm al link) this leads to sm aller tem perature rises and a decreased sensitivity of the bolom etric m ethod. C learly, the experimental sensitivity of the bolom etric m ethod will be optimized by operating in the low-frequency lim it: j j > r or $1 < r^2$. A consideration of the therm al di usivity and dimensions of the weak-link m ust therefore be part of any plan to increase the m odulation frequency.

Fig. 10 shows the frequency response of the sam – ple therm al stage in our apparatus when it was subjected to a sinusoidally varying heater power, norm alized to the static response. Included in the gure are ts to the distributed-heat-capacity m odel, Eq.A 2 and a single-pole low-pass lter response T (!) = T (! = 0) = 1 = 1 + 1 + 2 = 2. A lthough both curves t the data wellover m ost of the frequency range, the best-t value of the time constant in the lum ped-elem ent m odel corresponds to a heat capacity m uch larger than the calculated heat capacity of the sapphire sam ple stage. Instead, the value obtained from the t is approximately half the heat capacity of the quartz tube, indicating the correct physics is that of heat di usion in a distributed therm al system.

APPENDIX B:DESIGN STRATEGY FOR RECTANGULAR COAXIAL TRANSM ISSION LINE

In optim izing a m icrowave transm ission line for the bolom etric m easurem ent of surface resistance the guid-

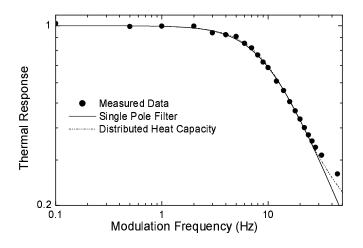


FIG.10: Low temperature (T = 1.3 K) m easurements of the dynamic thermal response of the quartz-tube bolometer platform. Curves on the plot show to using lumped and distributed heat capacity models.

ing aims must be: to deliver microwave power e ciently to the sample region, over as wide a frequency range as possible and with a well de ned polarization; to have regions of uniform microwave magnetic eld at the sample and reference positions; and, at these positions, to have a xed, frequency-independent ratio between the eld strengths. These aims can be met by using an impedance-matched (50), single-mode coaxial line, with rectangular cross section and a broad, at center conductor or septum, as shown in Fig. 11 (i). In addition, the dim ensions of the rectangular coaxial line should be chosen carefully, to prevent higher-order waveguide m odes from entering the operating frequency range of the experiment, as these modes break the symmetry in eld strength between sample and reference positions. This appendix outlines how to undertake the optim ization.

A rectangular coaxial line, like any two-conductor line, supports a transverse electrom agnetic (TEM) wave at all frequencies. Figure 11 (ii) shows its electric and magnetic eld con gurations. The TEM mode has the desirable property that its magnetic elds lie in a plane perpendicular to the direction of propagation, forming closed loops around the centre conductor. Conservation of magnetic ux then leads to a xed, frequency-independent relation between the elds on either side of the septum. These elds will also be quite hom ogeneous, as long as the height C of the centre conductor is large com pared to the gap (B D)=2 between the centre and outer conductors. To deliver m icrowave power e ciently to the sample region the characteristic in pedance of the TEM modemust be close to that of the cylindrical coaxial line used to bring m icrowaves into the cryostat. Gunston²⁴ has tabulated data on the impedance of rectangular coaxialline, and gives som e useful approxim ate form ulas. The following expression, due to Brackelm ann, is stated to be

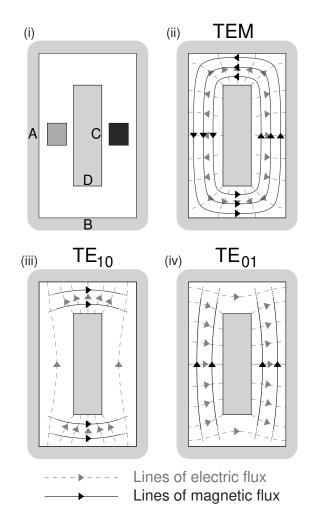


FIG.11: C ross sections of the rectangular coaxial transm ission line: (i) physical layout of the transm ission line show – ing dimensions (A;B;C;D) of the inner and outer conductors, and sam ple and reference positions (shaded squares); (ii) elds of the TEM mode, showing how continuity of ux and a broad, at inner conductor produce uniform, well polarized elds of equal intensity and opposite direction at the sam – ple and reference positions; (iii) elds of the TE₁₀ mode; and (iv) elds of the TE₀₁ mode. (M agnetic elds of the transverse electric modes contain a component along the direction of propagation and do not form closed loops in the transverse plane.) It is clear that the TE₀₁ mode is most harm fulto the operation of the broadband apparatus: its magnetic elds have high intensity at the sam ple and reference positions and break the balance that otherwise exists in the TEM mode.

accurate to 10% for D = B < 0.3 and C = A < 0.8:

$$Z_0 \frac{p_{-r}}{r} = 59.952 \ln \frac{A+B}{C+D}$$
; (B1)

where r is the relative permittivity of the dielectric lling the transm ission line.

We now come to the question of what places an upper lim it on the useful frequency range of the rectangular coaxial waveguide. At high frequencies our method,

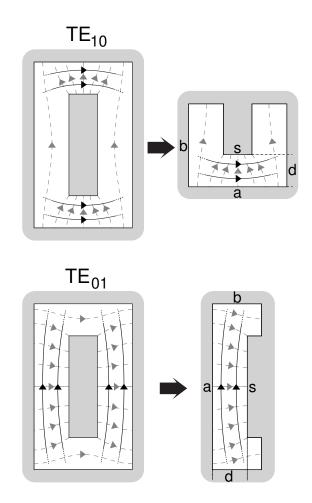


FIG.12: Conducting walls introduced along special electric equipotentials allow the waveguidem odes of rectangular coaxial line to be m apped onto the fundam ental mode of ridged waveguide, a problem extensively studied in the literature. The gures show the relabelling of dimensions in Pyle's notation²⁵ as a; b; d and s.

which incorporates an in-situ powerm eter, su ers a spectacular breakdown in the ratio of the relative strengths of the microwave magnetic elds at the sample and reference positions, as shown in Figure 5. This is caused by the presence of higher-order waveguide modes, which have di erent character from that of the TEM mode under the mid-plane re ection sym metries of the rectangular line. The waveguide modes with the lowest cut-o frequencies are the transverse electric modes TE₁₀ and TE₀₁, shown in Figures 11 (iii) and 11 (iv) respectively. These have the property that magnetic elds on opposite sides of the septum point in the same direction. The elds of the TEM mode, in contrast, are antiparallel, causing an admixture of TEM and TE modes to lack the important characteristic of equal eld intensities at sam ple and reference positions. Particularly dam aging is the TE₀₁ m ode, which is not screened by the septum and has high eld intensity in the vicinity of the sample and reference. In principle it is possible to avoid exciting the

transverse electric m odes by building a very symmetric transmission line. In practice, how ever, we nd this to be in possible | su ciently large symmetry-breaking perturbations are always present. Nevertheless, maintaining high symmetry is still desirable. A comparison of our results with calculations of the cut-o frequencies of the transverse electric modes show s that at frequencies where the higher order modes are free to propagate, they do not in mediately cause a breakdown in eld ratio: this only occurs when the transverse electric modes come into resonance. (This can be seen very clearly in Figure 5.) As a result, the range of operating frequency can be extended by as much as 50% just by shortening the nal section of transmission line and carefully designing the transition between the cylindrical and rectangular sections.

Optim izing the range of single-m ode operation of the rectangular transm ission line requires a method for calculating the cut-o frequencies of the TE $_{10}$ and TE $_{01}$ m odes. W hile wavequide m odes in two-conductor rectanqular transm ission lines have not been extensively studied, their eld con gurations can be mapped onto a more com m on geom etry: that of ridged waveguide. Figure 12 shows how. Electric equipotentials run perpendicular to lines of electric ux, and special equipotentials, corresponding to local minim a of the magnetic ux density, exist on the symmetry axes of the rectangle. A conducting wall can be introduced along these lines without disturbing the eld distributions, thereby mapping each m ode onto an equivalent ridged waveguide. Figure 12 illustrates the two di erent ways this is done, for the T E $_{10}$ and TE₀₁ modes respectively. A very early calculation of the cuto frequency of ridged waveguide was carried out by $Py e^{25}$ and is notable for its simplicity, generality and enduring accuracy when compared to more recent num erical m ethods.²⁶ Pyle's approach is to solve for the transverse resonance condition of the waveguide, which is equivalent to nding the cut-o frequency $!_{\rm c}$. W e have used this m ethod in our design process, as it is easy to implement (involving only algebraic equations) and is accurate to several percent except when the septum becomes very thin. The length 'of the rectangular line, the cut-o frequency, and the discontinuity capacitance of the cylindrical-to-rectangular transition together determ ine the resonant frequencies $!_{R}$ of the transverse electric modes. There are two limiting cases, corresponding to open-circuit (' = = 4) and short-circuit (' = = 2) term ination (where = 2 = k is the wavelength along the guide), that follow from the waveguide dispersion relation.

$$l_{\rm R}^2 = l_{\rm c}^2 + c^2 k^2 = l_{\rm c}^2 + \frac{4c^2}{2}$$
 (B2)

=
$$!_{c}^{2} + \frac{c^{2}}{4^{2}}$$
: open circuit (B3)

=
$$!_{c}^{2} + \frac{c^{2}}{2}$$
 : short circuit (B4)

A high capacitance for the TE modes at the transition from cylindrical to rectangular coax is clearly favourable:

it better approxim ates the short circuit term ination condition and leads to resonant frequencies at the upper end of the range. This e ect is responsible for the di erence in resonant frequencies between the scale model and the actual apparatus seen in Figure 5. There is, however, a trade-o to be made: too large a transition capacitance for the TEM mode will result in most of the microw ave power being re ected before it reaches the sam ple. The dimensions of the rectangular guide in our apparatus are A = 8:90 mm, B = 4:06 mm, C = 4:95 mm, D = 0.91 mm and ' = 6.60 mm. The cut-o frequencies for the ${\rm TE}_{10}$ and ${\rm TE}_{01}$ modes are calculated to be 19.68 GHz and 15.38 GHz respectively. The quarter wave-resonances would then occur at 22.72 GHz and 19.12 GHz, and the half wave resonances at 30.06 GHz and 27.44 GHz.

APPENDIX C:EXTRACTION OF $_1 \, (! \,)$ FROM R $_{\rm s} \, (! \,)$ M EASUREMENTS

In this appendix we show how the microwave conductivity spectrum of a superconductor can be obtained from a measurement of its frequency-dependent surface resistance. This process is similar to the extraction of conductivity spectra in the infra-red frequency range from re ectance measurements. In both cases, we begin with incomplete information about the electrodynamic response: the bolometric technique described in this paper measures only the resistive part of the surface impedance; and optical techniques typically obtain the magnitude, but not the phase, of the re ectance. How – ever, the conductivity $_1$ i $_2$ is a causal response function, and its real and imaginary parts are related by a K ram ers{K ronig transform :

$${}_{2}(!) = \frac{2!}{P} P \int_{0}^{Z_{1}} \frac{1}{2!} () \frac{1}{2!} d; \qquad (C1)$$

where P denotes the principle part of the integral. At rst sight we seem to have replaced one uncertainty, incomplete know ledge of the phase, by another, the nite frequency range over which the m easurem ents have been m ade. How ever, a suitable extrapolation of the data out of the m easured frequency range is usually possible and m akes the transform a well-de ned procedure in practice.

We consider the limit of local electrodynamics, in which the microwave surface impedance $\rm Z_{\,s}$ is related to the complex conductivity in a straightforward manner by the expression

$$Z_{s} = R_{s} + iX_{s} = \frac{i! \ 0}{1 \ i \ 2};$$
 (C2)

Very generally, the conductivity can be partitioned into a super uid part $_{\rm S}$, consisting of a zero-frequency delta function and an associated reactive term , and a norm aluid component $_{\rm N}$:

$$(!;T) = _{1S} i_{2S} + _{1N} i_{2N}$$
 (C3)

$$= \frac{n_{s}e^{2}}{m} (!) \frac{n_{s}e^{2}}{m!} + n_{N} i_{2N};$$

where m is the quasiparticle e ective mass. In the clean-lim it, where the quasiparticle scattering rate 1= is much less than the spectroscopic gap 2, sum-rule arguments enable a clean partitioning of the conduction electron density n into a super uid density n_s and a norm al-uid density $n_n = n$ n_s . In this type of generalized two-uid model, 27 the tem perature dependence of n_s is determined phenom enologically from measurements of the magnetic penetration depth through the relation

$$n_s(T)e^2 = m = [0^2(T)]^1$$
: (C4)

Applying this, we can write the conductivity at nite frequencies as

$$(!;T) = _{1N} (!;T) \quad i _{2N} (!;T) + \frac{1}{_{0}!^{-2}(T)} :$$
(C 5)

From Eq.C2 it is clear that R_s (!) is determ ined by both the real and in aginary parts of the conductivity. However, one simplication occurs at temperatures well below T_c , where few thermally excited quasiparticles exist, and the low frequency reactive response is dominated by the super uid. In this case, a good approximation to the relations becomes

$$R_{s}(!;T) = \frac{1}{2} {}^{2} {}^{2} {}^{3} (T) {}_{1}(!;T); \qquad (C 6)$$
$$X_{s}(!;T) = {}^{0} {}^{!} (T):$$

A thigher frequencies and tem peratures, a m ore com plete treatm ent would account for quasiparticle contributions to eld screening, which enter through $_{2N}$ (!;T). We use an iterative procedure to obtain the quasiparticle conductivity spectrum $_{1N}$ (!), starting from the good initial guess provided by Eq.C6. The process goes as follows. A phenom enological form that captures the key characteristics of the dataset but has no physical motivation, nam ely $_1$ (!) = $_0$ =[l + (!=)^Y], is tted to the spectrum and used to extrapolate out of the measured frequency range. The K ram ers{K ronig transform (Eq.C1) can then be applied to obtain $_{2N}$ (!). W ith $_{2N}$ (!) in

Perm anent address: Dept. of Physics, Sim on Fraser University, Burnaby, BC, Canada, V 5A 1S6.

- ^y Perm anent address: Dept. of Physics and A stronom y, M c-M aster University, H am ilton, ON, C anada, L8S 4M 1.
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hand, and with the super uid contribution to $_2$ known from measurements of the magnetic penetration depth, a new extraction of the conductivity from the R_s (!) data is made, this time using the exact expression, Eq. C 2. The whole procedure is repeated to self-consistency. We not that the procedure is stable and converges rapidly, and is not sensitive to the details of the high-frequency extrapolation. A lso, the corrections are quite small for the low temperature dataset shown in Fig. 8: at the highest temperature and frequency they amount to a 7% change in _1.

In addition, two independent experim ental checks give us further assurance that we obtain the correct conductivity spectra. We rst note that Eq. C2 contains an expression for the surface reactance X_s . Therefore, once we have measured the penetration depth and extracted the conductivity spectra from the R_s (!) data, we can predict the temperature dependence of the surface reactance at any frequency and compare with experim ent. W e have m ade this comparison at 22.7 G H z, with surface reactance data obtained on the same crystal, and nd excellent agreem ent. W e note that this is a frequency high enough for quasiparticle scattering to have a discernible e ect on the surface reactance.

A second veri cation of the conductivity extraction procedure is its ability to predict the spectral weight that resides outside the frequency window of the measurement. A corollary of the K ramers{K ronig relation C1 is the oscillator-strength sum rule

$$\frac{ne^2}{m} = \frac{2}{m} \sum_{0}^{Z_{1}} \frac{1}{1} (!;T)d!:$$
 (C7)

In a superconductor, in the clean limit, the sum rule requires that any spectral weight disappearing from the super uid density n_s (T) as temperature is raised must reappear as an increase in the frequency-integrated quasiparticle conductivity. We have carried out this com parison, which is shown in the inset of Fig. 8.²¹ The good agreement in the temperature dependence of the superuid and norm al-uid densities is a strong veri cation of both the analysis procedure and the bolom etric technique.

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